



# AMENDMENT TRANSMITTAL LETTER

Docket No.  
T2171.0196

Application No.  
09/873,580

Filing Date  
June 4, 2001

Examiner  
F. Toledo

Art Unit  
2823

Applicant(s): Harumitsu Fujita et al.

Invention: MULTI-VOLTAGE LEVEL SEMICONDUCTOR DEVICE AND ITS MANUFACTURE

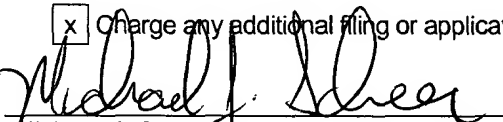
## TO THE COMMISSIONER FOR PATENTS

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

CLAIMS AS AMENDED					
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
Total Claims	4	- 8 =		x	
Independent Claims	1	- 1 =	0	x	
Multiple Dependent Claims (check if applicable) <input type="checkbox"/>					
Other fee (please specify):					
<b>TOTAL ADDITIONAL FEE FOR THIS AMENDMENT:</b>					

- ☒ Large Entity ☐ Small Entity
- ☐ No additional fee is required for this amendment.
- ☐ Please charge Deposit Account No. \_\_\_\_\_ in the amount of \$ \_\_\_\_\_.  
A duplicate copy of this sheet is enclosed.
- ☐ A check in the amount of \$ \_\_\_\_\_ to cover the filing fee is enclosed.
- ☒ The Commissioner is hereby authorized to charge and credit Deposit Account No. 04-1073  
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- ☒ Credit any overpayment.
- ☒ Charge any additional filing or application processing fees required under 37 CFR 1.16 and 1.17.

  
Michael J. Scheer  
Attorney Reg. No.: 34,425

Dated: March 12, 2002

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I hereby certify that this correspondence is being delivered with the U.S. Postal Service as Express Mail, Airbill No. EV 0595, to the US, in an envelope addressed to: Box Non-Fee Amendment, Commissioner for Patents, Washington, DC 20231, on the date shown below.

Dated: 3/12/02

Signature: *Diane Alberg*

(Diane Alberg)

03-13-02

2823

Docket No.: T2171.0196  
(PATENT)



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Patent Application of:  
Harumitsu Fujita

Application No.: 09/873,580

Group Art Unit: 2823

Filed: June 4, 2001

Examiner: F. Toledo

For: MULTI-VOLTAGE LEVEL  
SEMICONDUCTOR DEVICE AND ITS  
MANUFACTURE

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AMENDMENT

Box Non-Fee Amendment  
Commissioner for Patents  
Washington, DC 20231

Dear Sir:

In response to the Office Action mailed October 12, 2001, please amend the above-identified U.S. patent application as follows:

In the Specification:

Please amend the specification as follows:

On page 1, beneath the title:

This application is a divisional of 09/021,519 filed February 10, 1998, now U.S. Patent No. 6,271,572 which is based on Japanese patent application No. 9-28132, filed February 12, 1997, the whole contents of which are incorporated herein by reference.

In the Claims: